

# OKI semiconductor

## MSM41257A

### 262,144-WORD x 1-BIT DYNAMIC RAM (NIBBLE MODE TYPE)

#### GENERAL DESCRIPTION

The Oki MSM41257A is a fully decoded, dynamic NMOS random access memory organized as 262,144 words x 1 bit. The design is optimized for high-speed, high performance applications such as mainframe memory, buffer memory, peripheral storage and environments where low power dissipation and compact layout are required.

Multiplexed row and column address input permits MSM41257A housing in a standard 16 pin DIP or 18 pin PLCC. Pin-outs conform to the JEDEC approved pin out. Additionally, the MSM41257A offers new functional enhancements that make it more versatile than previous dynamic RAMs. CAS-before-RAS refresh feature provides an on-chip refresh capability.

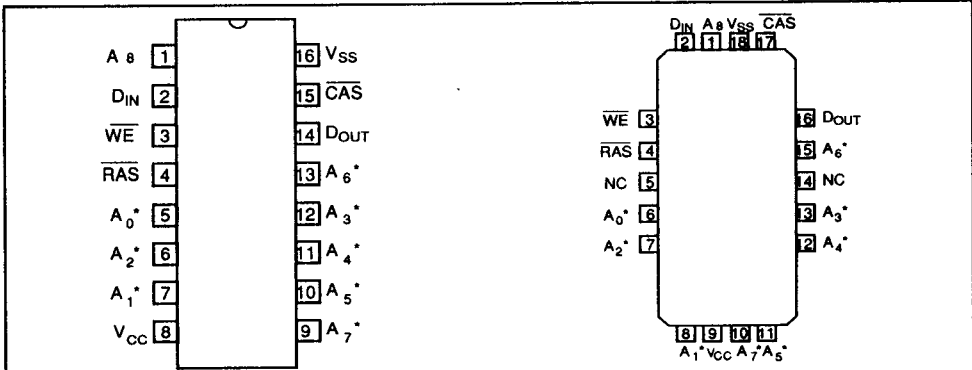
The MSM41257A is fabricated using silicon gate NMOS and Oki's advanced VLSI Polysilicon process. This process, coupled with single-transistor memory storage cells, permits maximum circuit density and minimum chip size. Dynamic circuitry, including the sense amplifiers, is employed in the design.

Clock timing requirements are noncritical, and power supply tolerance is very wide. All input and output are TTL compatible.

#### FEATURES

- 262,144 x 1 RAM, 16 or 18 pin package
- Silicon-gate, double poly NMOS, single transistor cell
- Row access time:
  - 100 ns max (MSM41257A-10)
  - 120 ns max (MSM41257A-12)
  - 150 ns max (MSM41257A-15)
- Cycle time:
  - 200 ns min (MSM41257A-10)
  - 220 ns min (MSM41257A-12)
  - 260 ns min (MSM41257A-15)
- Low power:
  - 330 mW active (MSM41257A-10)
  - 303 mW active (MSM41257A-12)
  - 275 mW active (MSM41257A-15)
  - 28 mW max standby
- Single +5V power supply,  $\pm 10\%$  tolerance
- TTL compatible, low capacitive load input
- Three-state TTL compatible output
- Gated CAS
- 256 refresh cycles/4 ms
- Common I/O capability using Early Write operation
- Output unlatched at cycle end to allow extended page boundary and two-dimensional chip select
- Read-Modify-Write and  $\overline{\text{RAS}}$ -only refresh capability
- On-chip latches for addresses and data-in
- On-chip substrate bias generator for high performance
- $\overline{\text{CAS}}$ -before- $\overline{\text{RAS}}$  refresh capability
- Nibble Mode capability

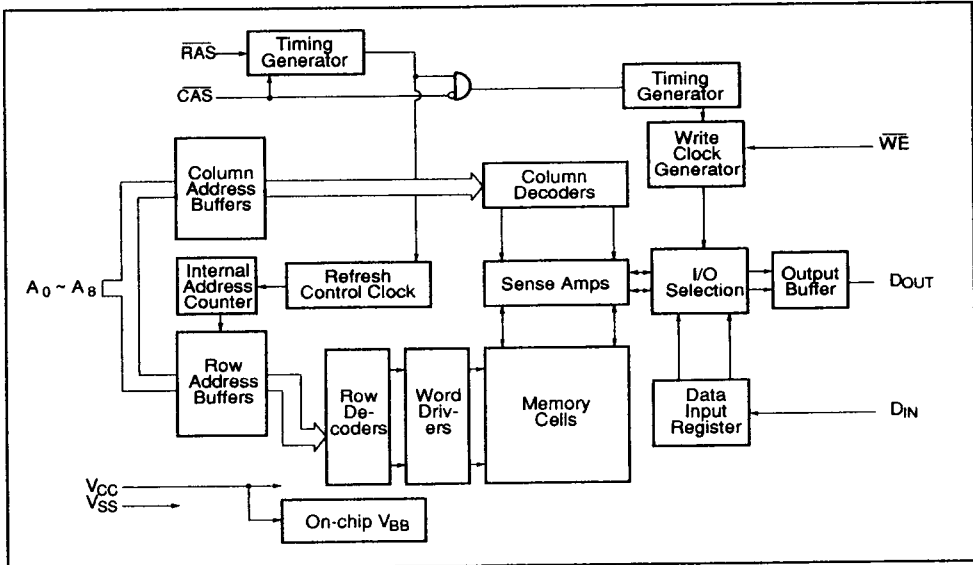
**PIN CONFIGURATION (TOP VIEW)**



\* Refresh Address

Pin Names	Function
A <sub>0</sub> ~ A <sub>8</sub>	Address Input
RAS	Row Address Strobe
CAS	Column Address Strobe
WE	Write Enable
D <sub>IN</sub>	Data Input
D <sub>OUT</sub>	Data Output
V <sub>CC</sub>	Power Supply (+5V)
V <sub>SS</sub>	Ground (0V)
NC	No Connection

**FUNCTIONAL BLOCK DIAGRAM**



**ELECTRICAL CHARACTERISTICS**  
**ABSOLUTE MAXIMUM RATINGS** (See Note)

Rating	Symbol	Conditions	Value	Unit
Voltage on any pin relative to V <sub>SS</sub>	V <sub>IN</sub> , V <sub>OUT</sub>	–	–1 to +7	V
Voltage on V <sub>CC</sub> supply relative to V <sub>SS</sub>	V <sub>CC</sub>	–	–1 to +7	V
Operating temperature	T <sub>opr</sub>	–	0 to 70	°C
Storage temperature	T <sub>stg</sub>	–	–55 to +150	°C
Power dissipation	P <sub>D</sub>	–	1.0	W
Short circuit output current	–	–	50	mA

Note: Permanent device damage may occur if ABSOLUTE MAXIMUM RATINGS are exceeded. Functional operation should be restricted to the conditions as detailed in the operational sections of this data sheet. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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**RECOMMENDED OPERATING CONDITIONS**  
 (Referenced to V<sub>SS</sub>)

Parameter	Symbol	Conditions	Value			Unit	Operating Temperature
			Min.	Typ.	Max.		
Supply voltage	V <sub>CC</sub>	–	4.5	5.0	5.5	V	0°C to +70°C
	V <sub>SS</sub>	–	0	0	0	V	
Input high voltage, all inputs	V <sub>IH</sub>	–	2.4	–	6.5	V	
Input low voltage, all inputs	V <sub>IL</sub>	–	–1.0	–	0.8	V	

**DC CHARACTERISTICS**

(Recommended operating conditions unless otherwise noted.)

Parameter	Symbol	Conditions	MSM41256A			Unit	Notes
			Min.	Typ.	Max.		
OPERATING CURRENT* Average power supply current (RAS, CAS cycling; t <sub>RC</sub> = min.)	MSM41257A-10	I <sub>CC1</sub>	-	-	-	60	mA
	MSM41257A-12			-	-	55	
	MSM41257A-15			-	-	50	
STANDBY CURRENT Power supply current (RAS = CAS = V <sub>IH</sub> )		I <sub>CC2</sub>	-	-	5.0	mA	
REFRESH CURRENT 1 Average power supply current (RAS cycling, CAS = V <sub>IH</sub> ; t <sub>RC</sub> = min.)	MSM41257A-10	I <sub>CC3</sub>	-	-	-	55	mA
	MSM41257A-12			-	-	50	
	MSM41257A-15			-	-	45	
NIBBLE MODE CURRENT* Average power supply current (RAS = V <sub>IL</sub> , CAS cycling; t <sub>NC</sub> = min.)	MSM41257A-10	I <sub>CC4</sub>	-	-	-	30	mA
	MSM41257A-12			-	-	27	
	MSM41257A-15			-	-	25	
REFRESH CURRENT 2 Average power supply current (CAS before RAS; t <sub>RC</sub> = min.)	MSM41257A-10	I <sub>CC5</sub>	-	-	-	55	mA
	MSM41257A-12			-	-	50	
	MSM41257A-15			-	-	45	
INPUT LEAKAGE CURRENT Input leakage current, any input (0V ≤ V <sub>IN</sub> ≤ 5.5V, all other pins not under test = 0V)		I <sub>LI</sub>	-	-10	-	10	μA
OUTPUT LEAKAGE CURRENT (Data out is disabled, 0V ≤ V <sub>OUT</sub> ≤ 5.5V)		I <sub>LO</sub>	-	-10	-	10	μA
OUTPUT LEVELS Output high voltage (I <sub>OH</sub> = -5 mA) Output low voltage (I <sub>OL</sub> = 4.2 mA)		V <sub>OH</sub> V <sub>OL</sub>	-	2.4	-	0.4	V V

\*: I<sub>CC</sub> depends on output loading and cycle rates. Specified values are obtained with the output open.

**CAPACITANCE**

(Ta = 25°C, f = 1 MHz)

Parameter	Symbol	Conditions	Value		Unit
			Min.	Max.	
Input capacitance (A <sub>0</sub> ~ A <sub>8</sub> , D <sub>IN</sub> )	C <sub>IN1</sub>	-	-	6	pF
Input capacitance (RAS, CAS, WE)	C <sub>IN2</sub>	-	-	7	pF
Output capacitance (D <sub>OUT</sub> )	C <sub>OUT</sub>	-	-	7	pF

\* Capacitance measured with Boonton Meter.

**AC CHARACTERISTICS**

(Recommended operating conditions unless otherwise noted.)

Notes 1,2,3

Parameter	Symbol	MSM41257A-10		MSM41257A-12		MSM41257A-15		Unit	Notes
		Min.	Max.	Min.	Max.	Min.	Max.		
Refresh period	$t_{REF}$	-	4	-	4	-	4	ms	-
Random read or write cycle time	$t_{RC}$	200	-	220	-	260	-	ns	-
Read-write cycle time	$t_{RWC}$	205	-	225	-	260	-	ns	-
Access time from $\overline{RAS}$	$t_{RAC}$	-	100	-	120	-	150	ns	4,5
Access time from $\overline{CAS}$	$t_{CAC}$	-	50	-	60	-	75	ns	4,5
Output buffer turn-off delay	$t_{OFF}$	0	30	0	30	0	30	ns	-
Transition time	$t_T$	3	50	3	50	3	50	ns	-
$\overline{RAS}$ precharge time	$t_{RP}$	90	-	90	-	100	-	ns	-
$\overline{RAS}$ pulse width	$t_{RAS}$	100	10,000	120	10,000	150	10,000	ns	-
$\overline{RAS}$ hold time	$t_{RSH}$	50	-	60	-	75	-	ns	-
$\overline{CAS}$ pulse width	$t_{CAS}$	50	10,000	60	10,000	75	10,000	ns	-
$\overline{CAS}$ hold time	$t_{CSH}$	100	-	120	-	150	-	ns	-
$\overline{RAS}$ to $\overline{CAS}$ delay time	$t_{RCD}$	25	50	25	60	25	75	ns	4
$\overline{CAS}$ to $\overline{RAS}$ set-up time	$t_{CRS}$	20	-	25	-	30	-	ns	-
Row address set-up time	$t_{ASR}$	0	-	0	-	0	-	ns	-
Row address hold time	$t_{RAH}$	15	-	15	-	15	-	ns	-
Column address set-up time	$t_{ASC}$	0	-	0	-	0	-	ns	-
Column address hold time	$t_{CAH}$	20	-	20	-	25	-	ns	-
Read command set-up time	$t_{RCS}$	0	-	0	-	0	-	ns	-
Read command hold time referenced to $\overline{CAS}$	$t_{RCH}$	0	-	0	-	0	-	ns	7
Read command hold time referenced to $\overline{RAS}$	$t_{RRH}$	20	-	20	-	20	-	ns	7
Write command set-up time	$t_{WCS}$	0	-	0	-	0	-	ns	6
Refresh counter test cycle time	$t_{RTC}$	315	-	355	-	415	-	ns	-
Refresh counter test $\overline{RAS}$ pulse width	$t_{TRAS}$	215	10,000	255	10,000	305	10,000	ns	-
Refresh counter test $\overline{CAS}$ precharge time	$t_{CPT}$	50	-	60	-	70	-	ns	-

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**AC CHARACTERISTICS (CONT.)**

(Recommended operating conditions unless otherwise noted.)

Parameter	Symbol	MSM41257A-10		MSM41257A-12		MSM41257A-15		Unit	Notes
		Min.	Max.	Min.	Max.	Min.	Max.		
Write command pulse width	$t_{WP}$	15	–	20	–	25	–	ns	–
Write command hold time	$t_{WCH}$	15	–	20	–	25	–	ns	–
Write command to $\overline{RAS}$ lead time	$t_{RWL}$	35	–	40	–	45	–	ns	–
Write command to $\overline{CAS}$ lead time	$t_{CWL}$	35	–	40	–	45	–	ns	–
Data-in set-up time	$t_{DS}$	0	–	0	–	0	–	ns	–
Data-in hold time	$t_{DH}$	20	–	20	–	25	–	ns	–
$\overline{CAS}$ to $\overline{WE}$ delay time	$t_{CWD}$	15	–	20	–	25	–	ns	6
Refresh set-up time for $\overline{CAS}$ referenced to $\overline{RAS}$	$t_{FCS}$	20	–	25	–	30	–	ns	–
Refresh hold time for $\overline{CAS}$ referenced to $\overline{RAS}$	$t_{FCH}$	20	–	25	–	30	–	ns	–
$\overline{CAS}$ precharge time (C before R cycle)	$t_{CPR}$	20	–	25	–	30	–	ns	–
$\overline{RAS}$ precharge to $\overline{CAS}$ active time	$t_{RPC}$	20	–	20	–	20	–	ns	–
Nibble mode read/write cycle time	$t_{NC}$	60	–	70	–	80	–	ns	–
Nibble mode read/write cycle time	$t_{NRWC}$	60	–	70	–	80	–	ns	–
Nibble mode access time	$t_{NCAC}$	–	25	–	30	–	35	ns	–
Nibble mode $\overline{CAS}$ pulse width	$t_{NCAS}$	25	–	30	–	35	–	ns	–
Nibble mode $\overline{CAS}$ precharge time	$t_{NCP}$	25	–	30	–	35	–	ns	–
Nibble mode read $\overline{RAS}$ hold time	$t_{NRRSH}$	25	–	30	–	35	–	ns	–
Nibble mode write $\overline{RAS}$ hold time	$t_{NWRSH}$	45	–	50	–	60	–	ns	–
Nibble mode $\overline{CAS}$ hold time referenced to $\overline{RAS}$	$t_{RNH}$	25	–	30	–	35	–	ns	–

**AC CHARACTERISTICS (CONT.)**

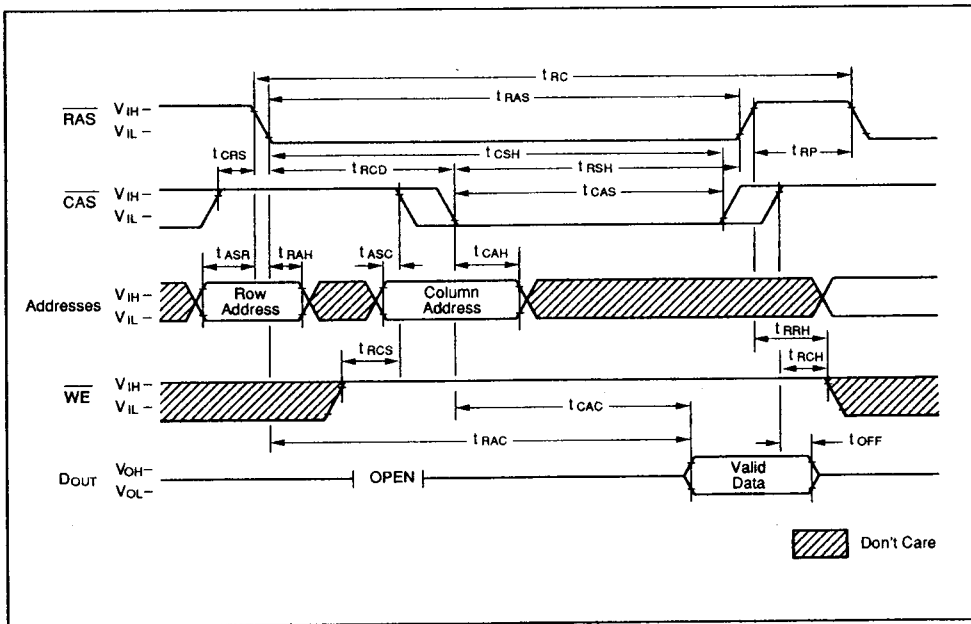
(Recommended operating conditions unless otherwise noted.)

Parameter	Symbol	MSM41257A-10		MSM41257A-12		MSM41257A-15		Unit	Notes
		Min.	Max.	Min.	Max.	Min.	Max.		
Refresh counter test cycle time	$t_{RTC}$	315	–	355	–	415	–	ns	–
Refresh counter test RAS pulse width	$t_{TRAS}$	215	10,000	255	10,000	305	10,000	ns	–
Refresh counter test $\overline{CAS}$ precharge time	$t_{CPT}$	50	–	60	–	70	–	ns	–

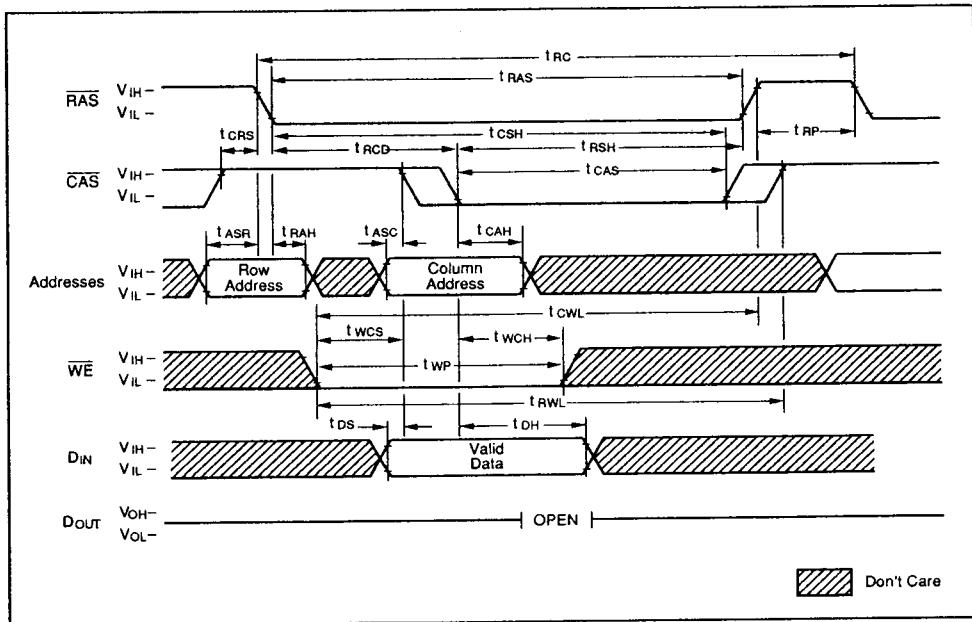
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- Notes: 1. An initial pause of 100  $\mu$ s is required after power-up followed by a minimum of any 8 RAS cycles (example: RAS-only refresh) before proper device operation is achieved.
2. The AC measurements assume the transition time ( $t_T$ ) = 5 ns.
3.  $V_{IH}$  (min.) and  $V_{IL}$  (max.) are reference levels for measuring the timing of the input signals. Transition times are measured between  $V_{IH}$  and  $V_{IL}$ .
4. Operating within the  $t_{RCd}$  (max.) limit insures that  $t_{RAC}$  (max.) can be met. The spec.  $t_{RCd}$  (max.) is for reference only. If  $t_{RCd}$  is greater than the specified  $t_{RCd}$  (max.) limit, then the access time will be controlled exclusively by  $t_{CAC}$ .
5. Measured using an equivalent load circuit of 2 TTL loads and 100pF.
6. The specs  $t_{wCS}$ ,  $t_{rWD}$ , and  $t_{cWD}$  are not restrictive operating parameters. They are included in the data sheet for reference only. If  $t_{wCS} \geq t_{wCS}$  (min.) the cycle is an Early Write cycle and data out remains in a high impedance state throughout the entire cycle. If  $t_{cWD} \geq t_{cWD}$  (min.) and  $t_{rWD} \geq t_{rWD}$  (min.), the cycle is a Read-Write cycle and the data out contains data read from the selected cell. If neither of the above sets of conditions is satisfied, the condition of data out is indeterminate at access time.
7. Either the  $t_{RRH}$  or the  $t_{RCH}$  spec. must be satisfied for a proper read cycle.

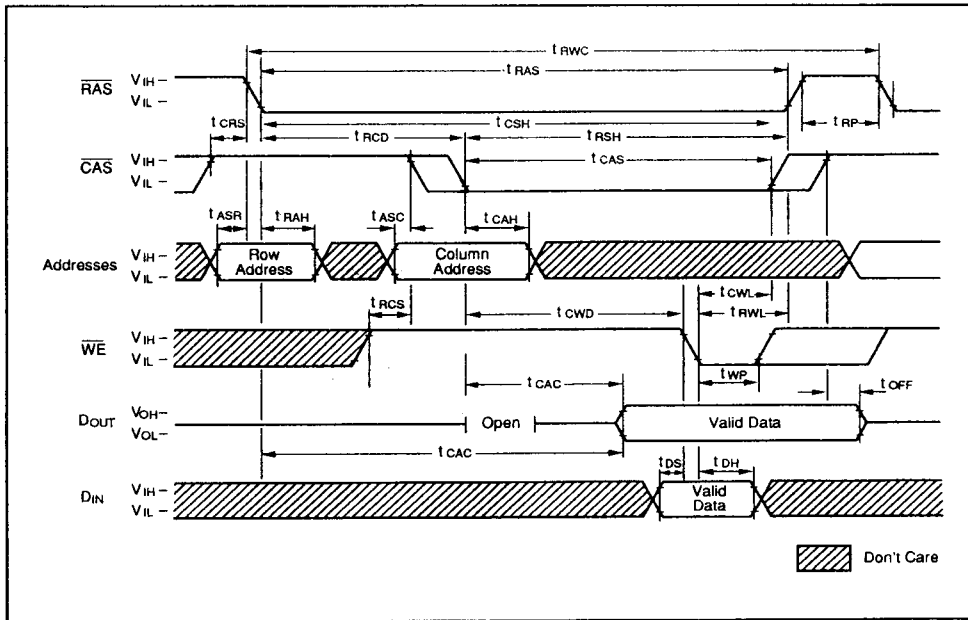
**READ CYCLE**



**WRITE CYCLE (EARLY WRITE)**

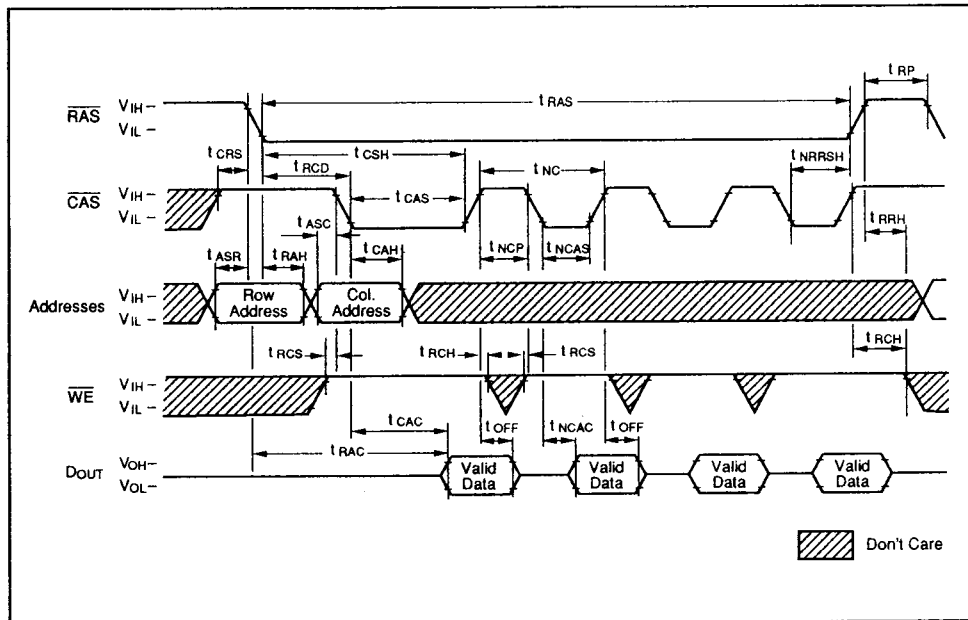


**READ-WRITE/READ-MODIFY-WRITE CYCLE**

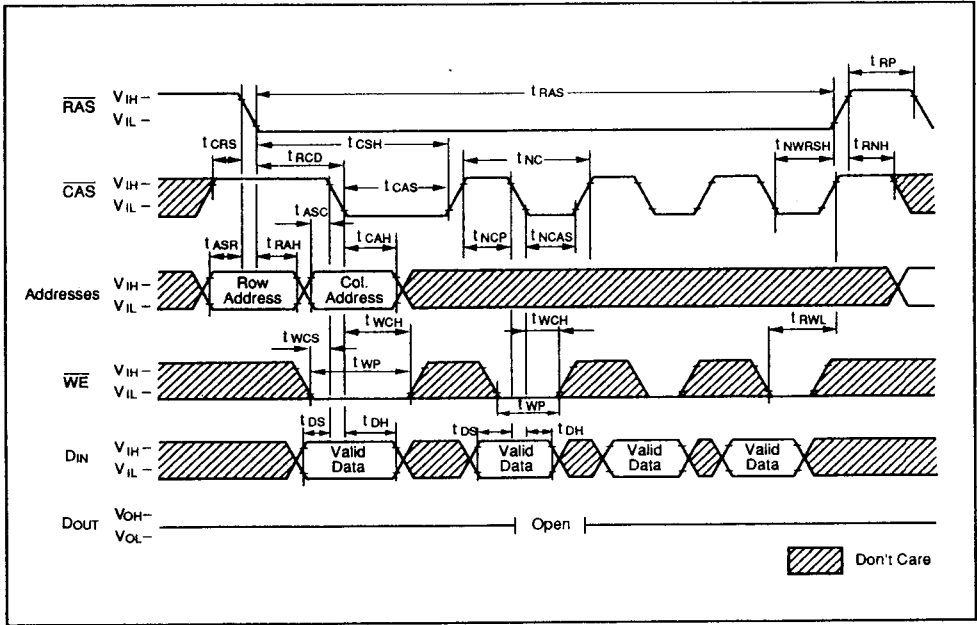


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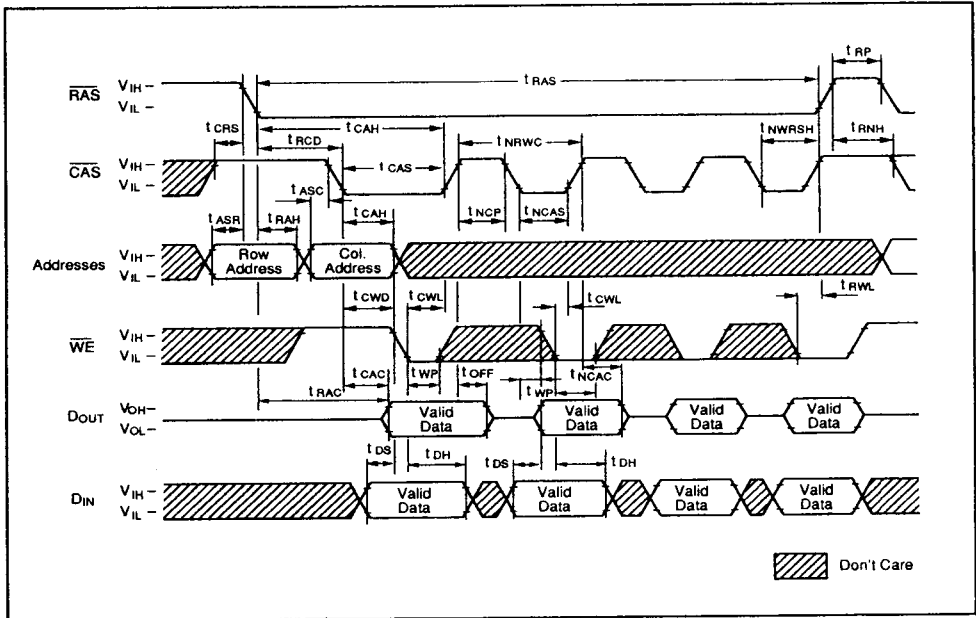
**NIBBLE MODE READ CYCLE**



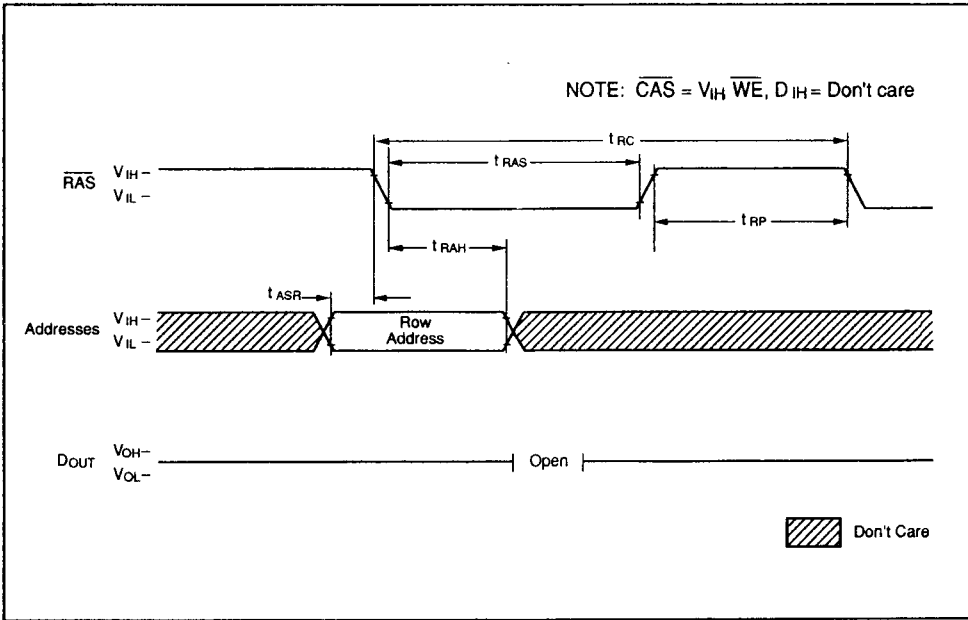
**NIBBLE MODE WRITE CYCLE**



**NIBBLE MODE READ-WRITE CYCLE**

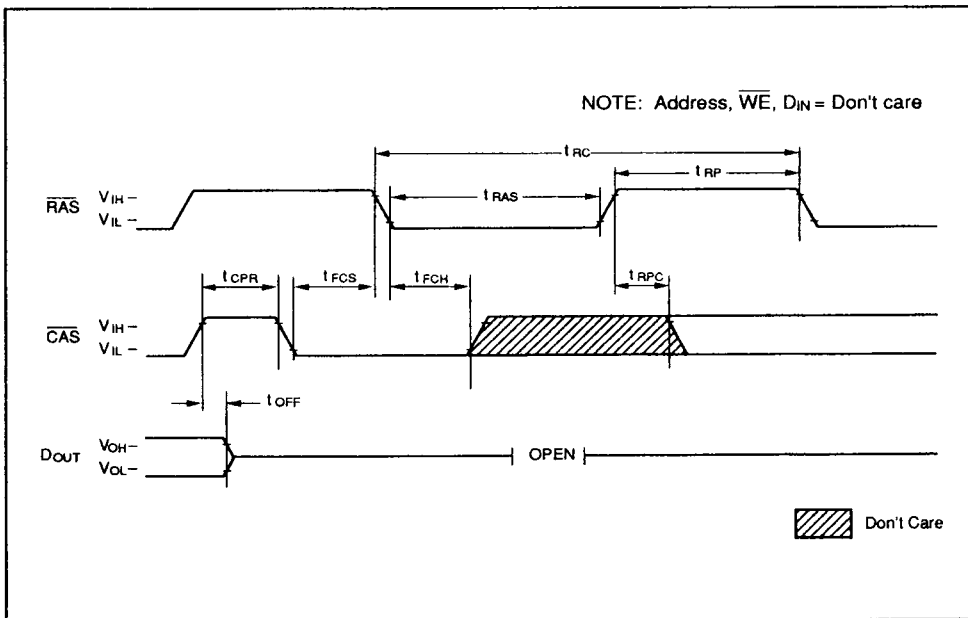


**RAS-ONLY REFRESH CYCLE**

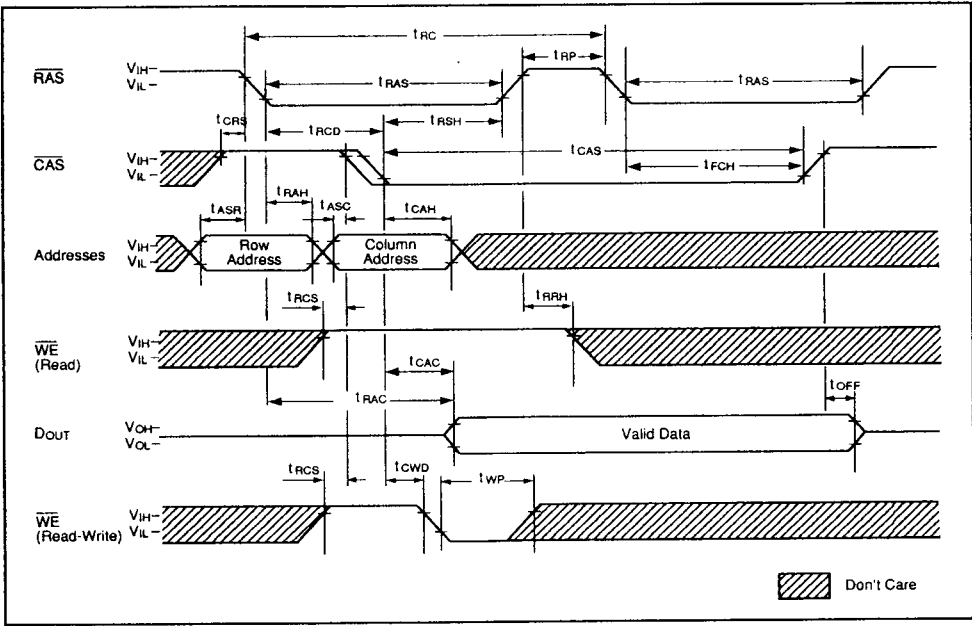


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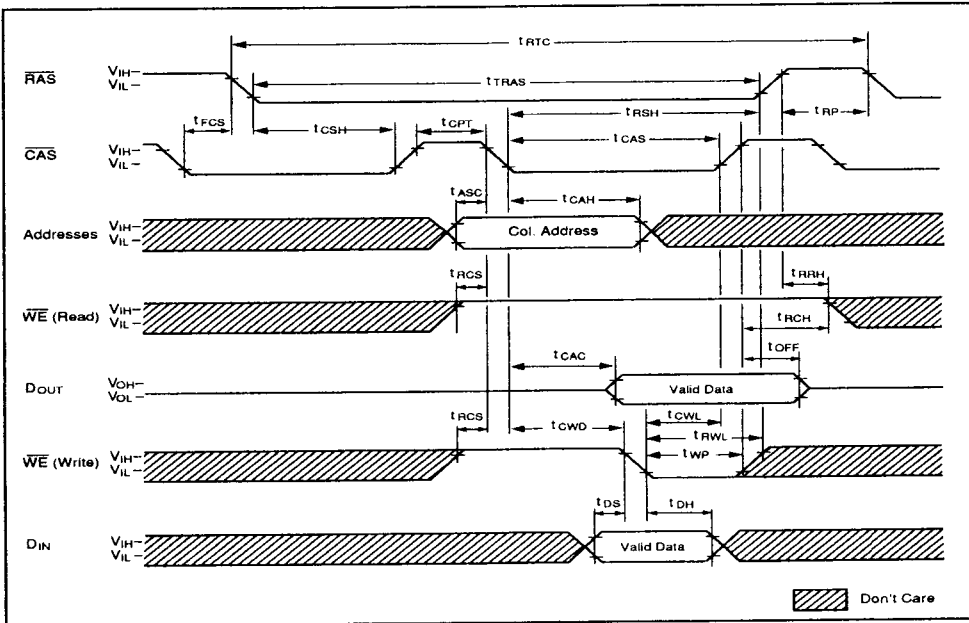
**CAS-BEFORE-RAS REFRESH CYCLE**



HIDDEN REFRESH CYCLE

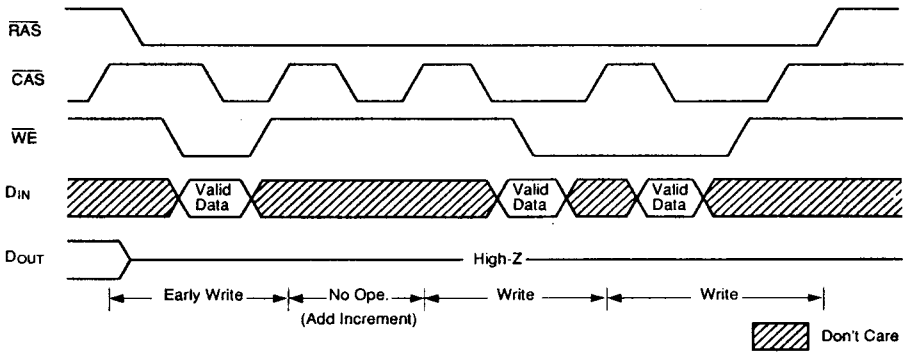


CAS-BEFORE-RAS REFRESH COUNTER TEST CYCLE

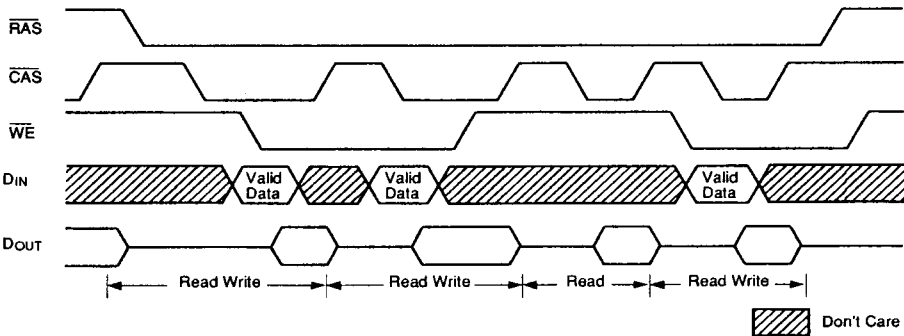


**NIBBLE MODE**

1) The case of first nibble cycle is Early Write



2) The case of first nibble cycle is delayed write (Read-Write)



**MSM41257 BIT MAP (PHYSICAL-DECIMAL)**

Pin 16

252	253	254	255		3	2	1	0	COLUMN DECODER	256	257	258	259		511	510	509	508
128	128	128	128		128	128	128	128		256	128	128	128		128	128	128	128
252	253	254	255		3	2	1	0		256	257	258	259		511	510	509	508
384	384	384	384		384	384	384	384		384	384	384	384		384	384	384	384
252	253	254	255		3	2	1	0		256	257	258	259		511	510	509	508
129	129	129	129		129	129	129	129		129	129	129	129		129	129	129	129
252	253	254	255		3	2	1	0		256	257	258	259		511	510	509	508
385	385	385	385		385	385	385	385		385	385	385	385		385	385	385	385
252	253	254	255		3	2	1	0		256	257	258	259		511	510	509	508
254	254	254	254		254	254	254	254		254	254	254	254		254	254	254	254
252	253	254	255		3	2	1	0		256	257	258	259		511	510	509	508
510	510	510	510		510	510	510	510		510	510	510	510		510	510	510	510
252	253	254	255		3	2	1	0		256	257	258	259		511	510	509	508
255	255	255	255		255	255	255	255		255	255	255	255		255	255	255	255
252	253	254	255		3	2	1	0		256	257	258	259		511	510	509	508
511	511	511	511		511	511	511	511	511	511	511	511		511	511	511	511	

ROW DECODER			
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ROW DECODER			
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252	253	254	255		3	2	1	0	COLUMN DECODER	256	257	258	259		511	510	509	508
383	383	383	383		383	383	383	383		383	383	383	383		383	383	383	383
252	253	254	255		3	2	1	0		256	257	258	259		511	510	509	508
127	127	127	127		127	127	127	127		127	127	127	127		127	127	127	127
252	253	254	255		3	2	1	0		256	257	258	259		511	510	509	508
382	382	382	382		382	382	382	382		382	382	382	382		382	382	382	382
252	253	254	255		3	2	1	0		256	257	258	259		511	510	509	508
126	126	126	126		126	126	126	126		126	126	126	126		126	126	126	126
252	253	254	255		3	2	1	0		256	257	258	259		511	510	509	508
257	257	257	257		257	257	257	257		257	257	257	257		257	257	257	257
252	253	254	255		3	2	1	0		256	257	258	259		511	510	509	508
1	1	1	1		1	1	1	1		1	1	1	1		1	1	1	1
252	253	254	255		3	2	1	0		256	257	258	259		511	510	509	508
256	256	256	256		256	256	256	256		256	256	256	256		256	256	256	256
252	253	254	255		3	2	1	0		256	257	258	259		511	510	509	508
0	0	0	0		0	0	0	0	0	0	0	0		0	0	0	0	

256	257	258	259		511	510	509	508	COLUMN DECODER	256	257	258	259		511	510	509	508
383	383	383	383		383	383	383	383		383	383	383	383		383	383	383	383
256	257	258	259		511	510	509	508		256	257	258	259		511	510	509	508
127	127	127	127		127	127	127	127		127	127	127	127		127	127	127	127
256	257	258	259		511	510	509	508		256	257	258	259		511	510	509	508
382	382	382	382		382	382	382	382		382	382	382	382		382	382	382	382
256	257	258	259		511	510	509	508		256	257	258	259		511	510	509	508
126	126	126	126		126	126	126	126		126	126	126	126		126	126	126	126
256	257	258	259		511	510	509	508		256	257	258	259		511	510	509	508
257	257	257	257		257	257	257	257		257	257	257	257		257	257	257	257
256	257	258	259		511	510	509	508		256	257	258	259		511	510	509	508
1	1	1	1		1	1	1	1		1	1	1	1		1	1	1	1
256	257	258	259		511	510	509	508		256	257	258	259		511	510	509	508
256	256	256	256		256	256	256	256		256	256	256	256		256	256	256	256
256	257	258	259		511	510	509	508		256	257	258	259		511	510	509	508
0	0	0	0		0	0	0	0	0	0	0	0		0	0	0	0	

A8 ROW = LOW REFRESH ADDRESS

(0-255)

A8 ROW = HIGH REFRESH ADDRESS

(0-255)



Pin8  
:CELL

A = ROW ADDRESS (DECIMAL)  
B = COLUMN ADDRESS (DECIMAL)

ROW ADDRESS  
8N+6, 8N+7, 8N, 8N+1  
8N+2, 8N+3, 8N+4, 8N+5  
8N+6, 8N+7, 8N, 8N+1  
8N+2, 8N+3, 8N+4, 8N+5  
N=0, 1, 2, ..., 63

COLUMN ADDRESS  
2N  
2N  
2N+1  
2N+1  
N=0, 1, 2, ..., 255

:POSITIVE  
:NEGATIVE  
:NEGATIVE  
:POSITIVE